SCES275G - JUNE 1999 - REVISED AUGUST 2003

- Operates From 2.7 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max tpd of 6.3 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Ioff and Power-Up 3-State Support Hot Insertion
- **Supports Mixed-Mode Signal Operation on** All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

#### DB, DW, N, NS, OR PW PACKAGE (TOP VIEW) 20 🛮 V<sub>CC</sub> DIR [ A1 **1** 2 19 TOE A2 **∏** 3 18 **|** B1 A3 **∏** 4 17 B2 A4 **∏** 5 16 **∏** B3 А5 П 15 **∏** B4 A6 **∏** 7 14 **∏** B5 A7 **∏** 8 13 ∏ B6 12 **| B7**

11 **∏** B8

А8 П 9

GND 10

## description/ordering information

This octal bus transceiver is designed for 2.7-V to 3.6-V  $V_{CC}$  operation.

The SN74LVCZ245A is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so the buses are effectively isolated.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

When V<sub>CC</sub> is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using Ioff and power-up 3-state. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

### ORDERING INFORMATION

TA	PACK	AGET	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 20	SN74LVCZ245AN	SN74LVCZ245AN
	SOIC - DW	Tube of 25	SN74LVCZ245ADW	LVCZ245A
	30IC - DW	Reel of 2000	SN74LVCZ245ADWR	LVCZZ43A
4000 to 0500	SOP - NS	Reel of 2000	SN74LVCZ245ANSR	LVCZ245A
-40°C to 85°C	SSOP – DB	Reel of 2000	SN74LVCZ245ADBR	CV245A
		Tube of 70	SN74LVCZ245APW	CV245A
	TSSOP – PW	Reel of 2000	SN74LVCZ245APWR	CV245A
		Reel of 250	SN74LVCZ245APWT	CV245A

<sup>†</sup>Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



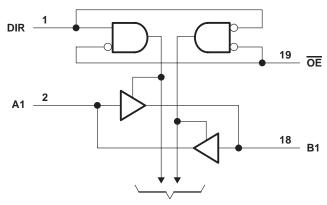
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#### **FUNCTION TABLE**

INP	UTS	OPERATION				
OE	DIR	OPERATION				
L	L	B data to A bus				
L	Н	A data to B bus				
Н	Χ	Isolation				

## logic diagram (positive logic)



To Seven Other Channels

# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>		
Voltage range applied to any output in the high-	impedance or power-off state, VO	
(see Note 1)		–0.5 V to 6.5 V
Voltage range applied to any output in the high	. 0	
(see Notes 1 and 2)		$\dots$ –0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )		–50 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)		
Continuous output current, IO		
Continuous current through V <sub>CC</sub> or GND		
Package thermal impedance, $\theta_{\text{JA}}$ (see Note 3):		
, <b>3</b> , , ,	DW package	58°C/W
	N package	
	NS package	60°C/W
	PW package	
Storage temperature range, T <sub>sta</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
  - 2. The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
  - 3. The package thermal impedance is calculated in accordance with JESD 51-7.



# recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.7	3.6	V
VIH	High-level input voltage $V_{CC} = 2.7 \text{ V}$	' to 3.6 V	2		V
V <sub>IL</sub>	Low-level input voltage $V_{CC} = 2.7 \text{ V}$	' to 3.6 V		0.8	V
VI	Input voltage		0	5.5	V
\/a	Output voltage High or low :	state	0	VCC ,	V
Vo	3-state		0	5.5	]
lou	V <sub>CC</sub> = 2.7 V			-12	mA
ЮН	High-level output current VCC = 3 V			-24	IIIA
lai	V <sub>CC</sub> = 2.7 V	'		12	mA
lor	Low-level output current VCC = 3 V			24	
Δt/Δν	Input transition rise or fall rate			6	ns/V
Δt/ΔVCC	Power-up ramp rate		150		μs/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P/	ARAMETER	TEST CONDITI	IONS	VCC	MIN	TYP <sup>†</sup>	MAX	UNIT
		I <sub>OH</sub> = -100 μA		2.7 V to 3.6 V	V <sub>CC</sub> -0.2			
		10 mA	2.7 V	2.2			V	
VOH		$I_{OH} = -12 \text{ mA}$	3 V	2.4			V	
		I <sub>OH</sub> = -24 mA		3 V	2.2			
		I <sub>OL</sub> = 100 μA		2.7 V to 3.6 V			0.2	
VOL				2.7 V			0.4	V
		I <sub>OL</sub> = 24 mA		3 V			0.55	
l <sub>l</sub>	Control inputs	V <sub>I</sub> = 0 to 5.5 V		3.6 V			±5	μΑ
l <sub>off</sub>	-	V <sub>I</sub> or V <sub>O</sub> = 5.5 V		0			±5	μΑ
loz‡		V <sub>O</sub> = 0 to 5.5 V		3.6 V			±5	μΑ
lozpu		$V_O = 0.5 \text{ V to } 2.5 \text{ V},$	OE = don't care	0 to 1.5 V			±5	μА
I <sub>OZPD</sub>		$V_O = 0.5 \text{ V to } 2.5 \text{ V},$	OE = don't care	1.5 V to 0			±5	μΑ
1		V <sub>I</sub> = V <sub>CC</sub> or GND	1- 0	261/			100	
Icc		3.6 V ≤ V <sub>I</sub> ≤ 5.5 V§	IO = 0	3.6 V	100		100	μΑ
ΔlCC	$\Delta I_{CC}$ One input at $V_{CC} - 0.6 \text{ V}$ , Other		inputs at V <sub>CC</sub> or GND	2.7 V to 3.6 V			100	μΑ
Ci	Control inputs	$V_I = V_{CC}$ or GND	·	3.3 V		4	·	pF
Cio	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		6		pF



<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C. ‡ For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current. § This applies in the disabled state only.

# SN74LVCZ245A OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

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# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

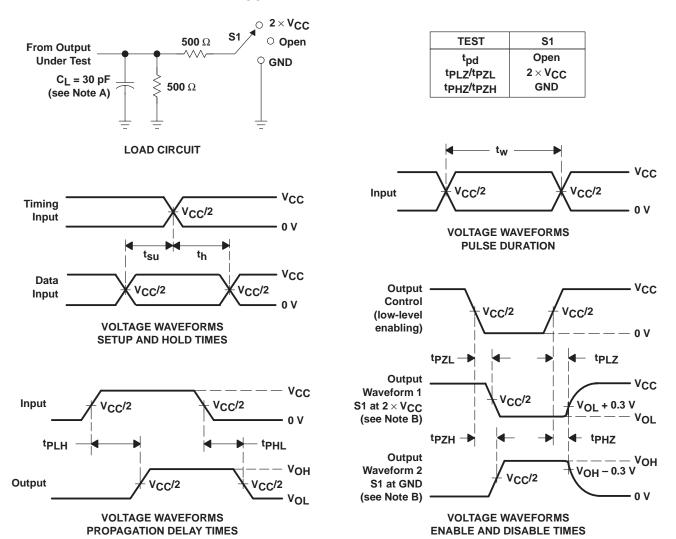
PARAMETER	FROM	FROM TO (INPUT) (OUTPUT)		V <sub>CC</sub> =	3.3 V 3 V	UNIT
	(1141 01)	(0011 01)	MIN MAX	MIN	MAX	
<sup>t</sup> pd	A or B	B or A	7.3	1.5	6.3	ns
t <sub>en</sub>	ŌĒ	A or B	9.5	1.5	8.5	ns
<sup>t</sup> dis	ŌĒ	A or B	8.5	1.7	7.5	ns

# operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 3.3 V TYP	UNIT
Const	Power dissipation capacitance per transceiver	Outputs enabled	f = 10 MHz	42	PF
Cpd		Outputs disabled	T = TO MINZ	3	рг



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



- NOTES: A. C<sub>I</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpl 7 and tpH7 are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tpLH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow (5)		(6)
SN74LVCZ245ADBR	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245ADBR.B	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245ADWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A
SN74LVCZ245ADWR.B	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A
SN74LVCZ245ANSR	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A
SN74LVCZ245ANSR.B	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCZ245A
SN74LVCZ245APW	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245APW.B	Active	Production	TSSOP (PW)   20	70   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245APWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245APWR.B	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245APWT	Active	Production	TSSOP (PW)   20	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A
SN74LVCZ245APWT.B	Active	Production	TSSOP (PW)   20	250   SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CV245A

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# PACKAGE OPTION ADDENDUM

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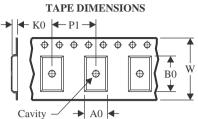
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# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





	•
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

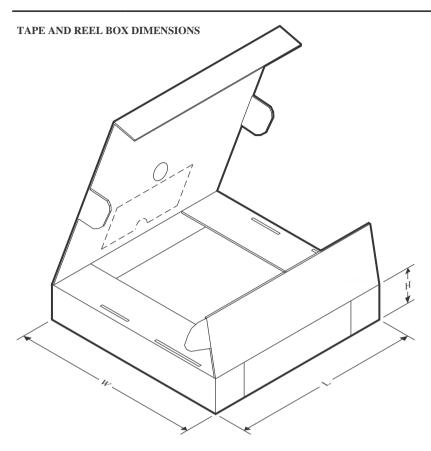


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCZ245ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVCZ245ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVCZ245ANSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVCZ245APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVCZ245APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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#### \*All dimensions are nominal

7 111 011110110110110 0110 11011111101							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCZ245ADBR	SSOP	DB	20	2000	353.0	353.0	32.0
SN74LVCZ245ADWR	SOIC	DW	20	2000	356.0	356.0	45.0
SN74LVCZ245ANSR	SOP	NS	20	2000	356.0	356.0	45.0
SN74LVCZ245APWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74LVCZ245APWT	TSSOP	PW	20	250	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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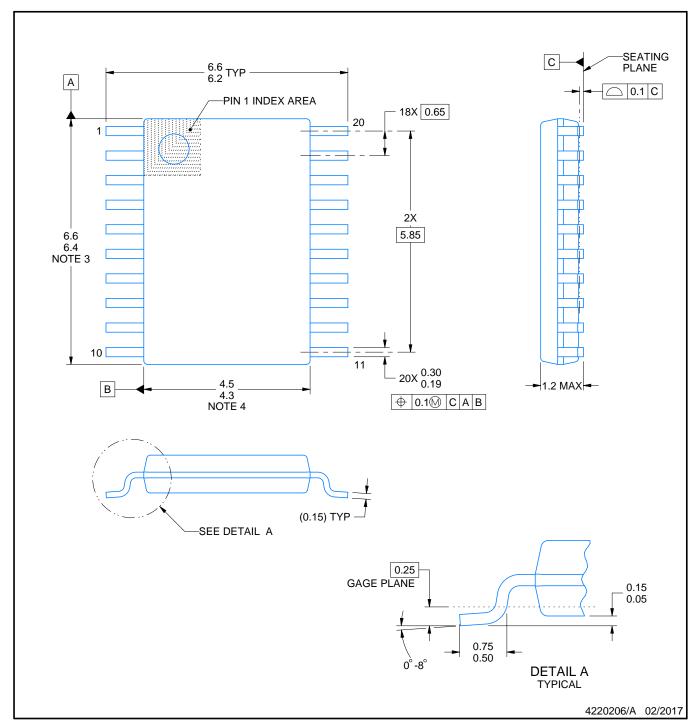
## **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVCZ245APW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVCZ245APW.B	PW	TSSOP	20	70	530	10.2	3600	3.5





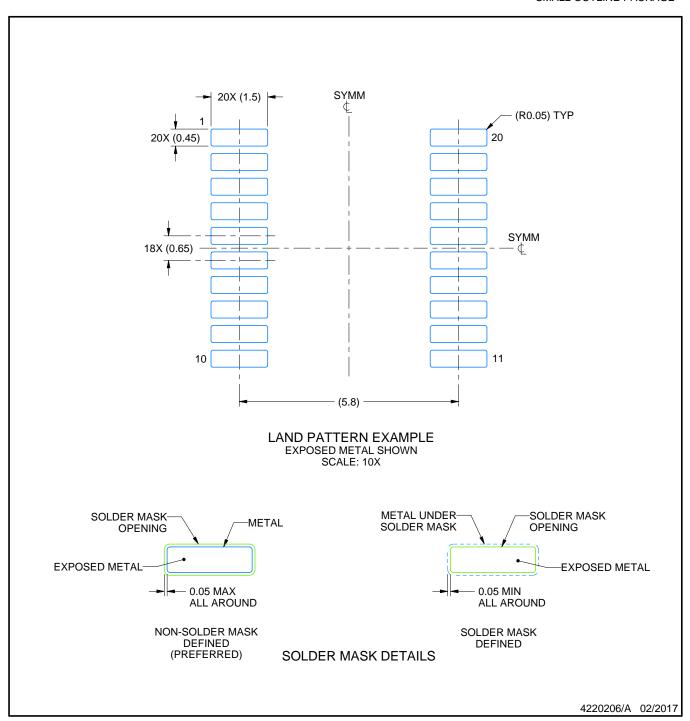
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



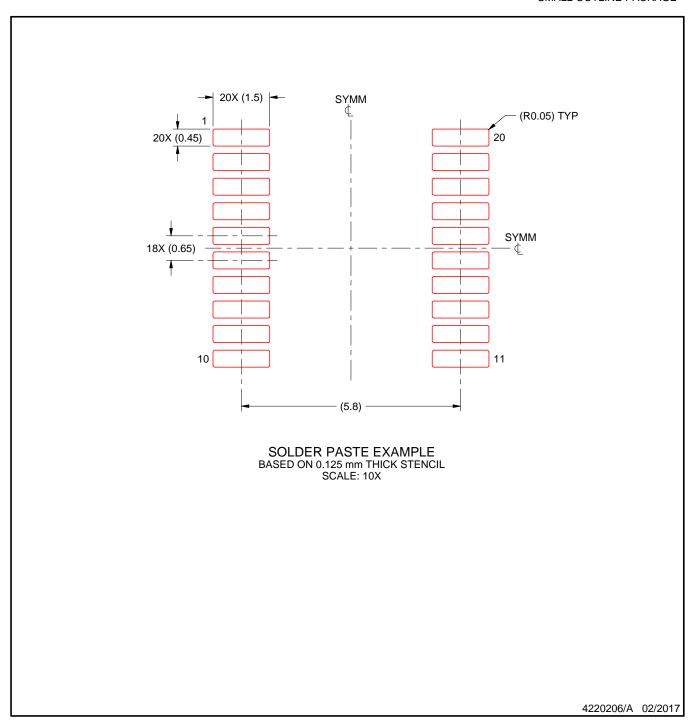


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



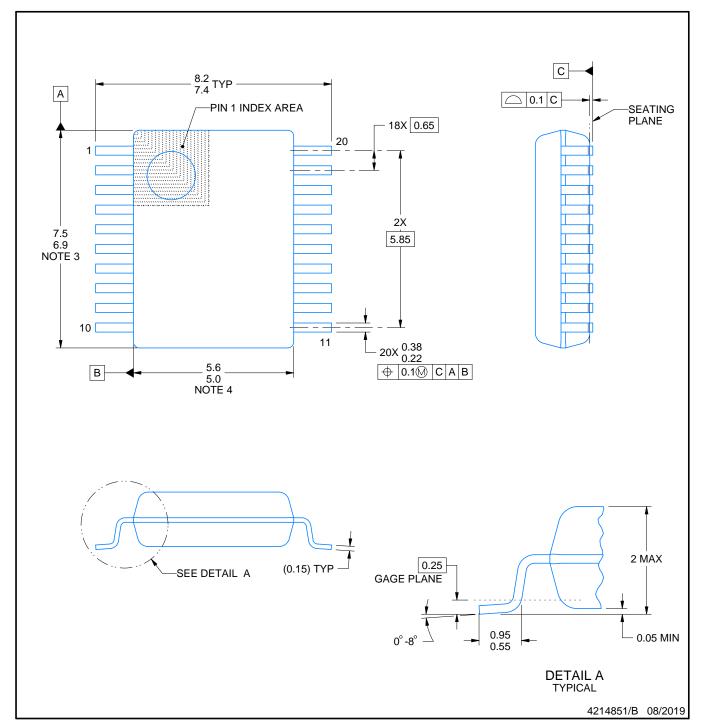


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







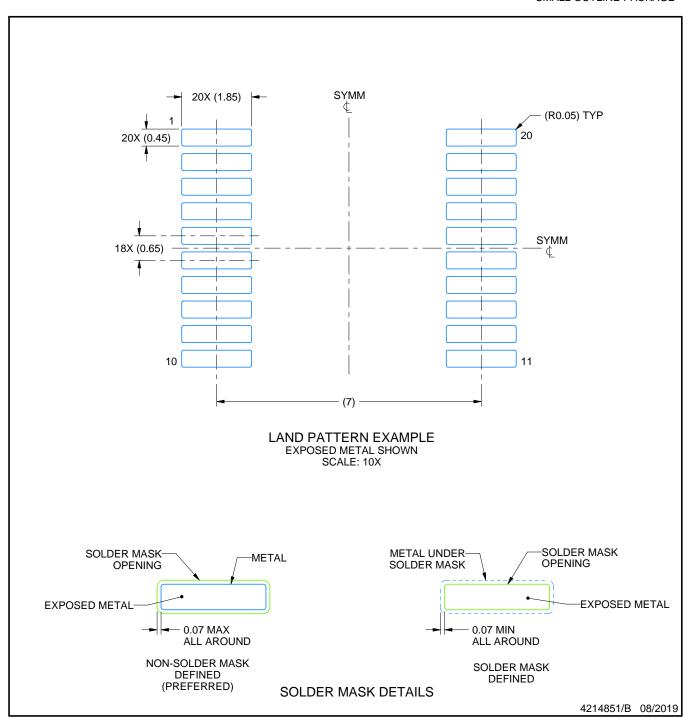
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



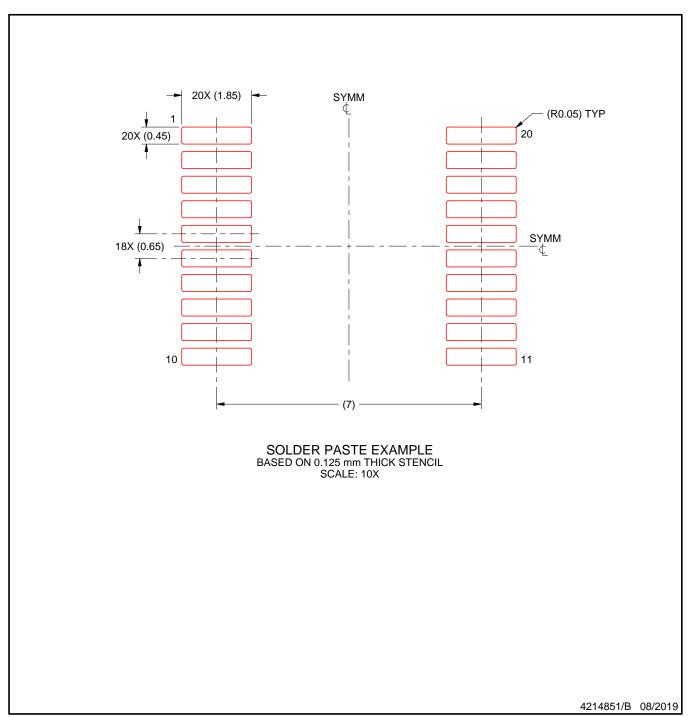


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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